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Vishay General Semiconductor

### **Dual Common-Cathode High-Voltage Schottky Rectifier**

Low Leakage Current 5.0 µA





PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>RRM</sub>	150 V				
I <sub>FSM</sub>	200 A				
V <sub>F</sub>	0.75 V				
T <sub>J</sub> max.	175 °C				

#### **FEATURES**





Low forward voltage drop

• High frequency operation

• Solder dip 275 °C max., 10 s per JESD 22-B106

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





## TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection applications.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	MBR20H150CT	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	150	V		
Working peak reverse voltage	$V_{RWM}$	150	V		
Maximum DC blocking voltage	$V_{DC}$	150	V		
Maximum average featured rectified current	per device	I <sub>F(AV)</sub>	20	А	
Maximum average forward rectified current	per diode		10		
Peak forward surge current 8.3 ms single half sine-wave on rated load per diode	I <sub>FSM</sub>	200	А		
Peak repetitive reverse current per diode at $t_p = 2 \mu s$ , 1 k	Hz	IRRM	1.0	Α	
Peak non-repetitive reverse surge energy per diode (8/20	E <sub>RSM</sub>	10	mJ		
Non-repetitive avalanche energy per diode at 25 °C, I <sub>AS</sub> =	E <sub>AS</sub>	11.25	mJ		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C		
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V <sub>AC</sub>	1500	V	

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.90	V
	I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C		0.75	
	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C		0.99	
	I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C		0.86	
Maximum reverse current per diode at working peak reverse voltage		T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(1)</sup>	5.0	μΑ
		T <sub>J</sub> = 125 °C		1.0	mA

#### **Notes**

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	4.2	2.2	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H150CT-E3/45	2.06	45	50/tube	Tube	
ITO-220AB	MBRF20H150CT-E3/45	2.20	45	50/tube	Tube	
TO-262AA	SB20H150CT-1E3/45	1.58	45	50/tube	Tube	

#### Note

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

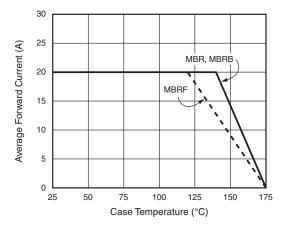


Fig. 1 - Forward Derating Curve (Total)

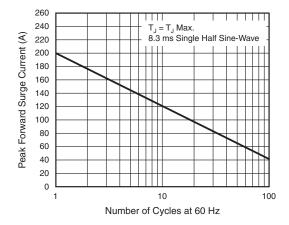


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

<sup>(1)</sup> AEC-Q101 qualified



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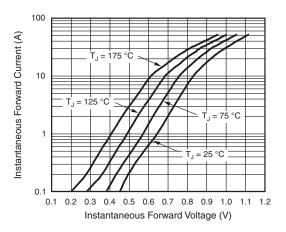
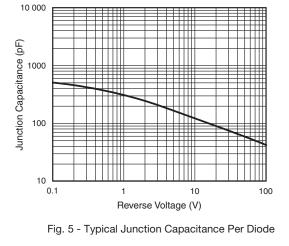


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



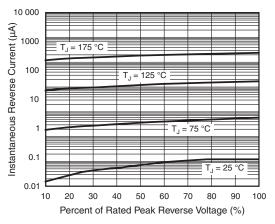


Fig. 4 - Typical Reverse Characteristics Per Diode

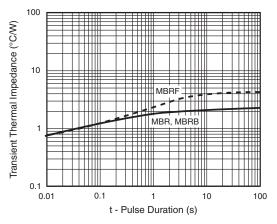


Fig. 6 - Typical Transient Thermal Impedance Per Diode

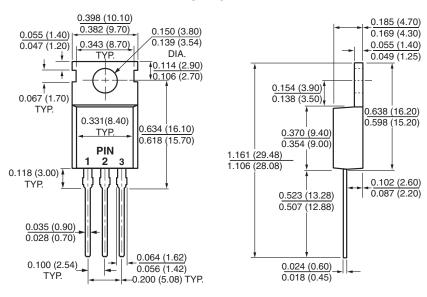


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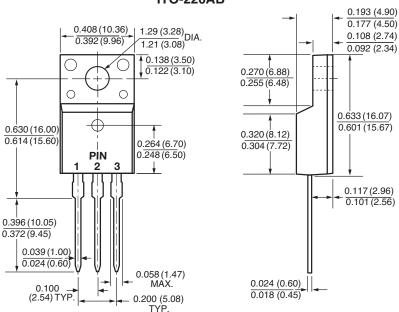
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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

#### **TO-220AB**



### ITO-220AB



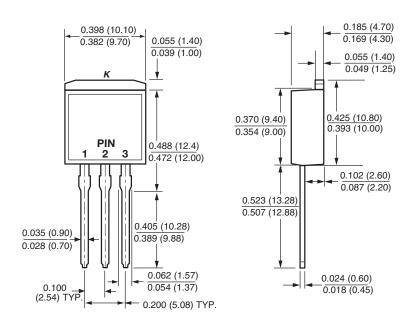


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### **TO-262AA**







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